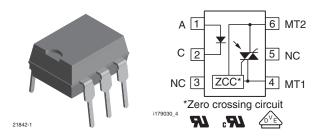


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### Vishay Semiconductors

# Optocoupler, Phototriac Output, Zero Crossing, High dV/dt, Low Input Current



#### **DESCRIPTION**

The VO4154 and VO4156 consists of a GaAs IRLED optically coupled to a photosensitive zero crossing TRIAC packaged in a DIP-6 package.

High input sensitivity is achieved by using an emitter follower phototransistor and a cascaded SCR predriver resulting in an LED trigger current of 1.6 mA for bin D, 2 mA for bin H, and 3 mA for bin M.

The new phototriac zero crossing family uses a proprietary dV/dt clamp resulting in a static dV/dt of greater than 5  $kV/\mu s$ .

The VO4154 and VO4156 isolates low-voltage logic from 120  $V_{AC}$ , 240  $V_{AC}$ , and 380  $V_{AC}$  lines to control resistive, inductive, or capacitive loads including motors, solenoids, high current thyristors or TRIAC and relays.

### **FEATURES**

- High static dV/dt 5 kV/µs
- High input sensitivity I<sub>FT</sub> = 1.6 mA, 2 mA, and 3 mA
- 300 mA on-state current
- · Zero voltage crossing detector
- 400 V and 600 V blocking voltage
- Isolation rated voltage 4420 V<sub>RMS</sub>
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912">www.vishay.com/doc?99912</a>

#### **APPLICATIONS**

- Solid-state relays
- · Industrial controls
- Office equipment
- Consumer appliances

#### **AGENCY APPROVALS**

- UL1577, file no. E52744, double protection
- cUL file no. E52744, equivalent to CSA bulletin 5A
- DIN EN 60747-5-5 (VDE 0884-5), available with option 1

ORDERING INFORMATION							
PART NUMBER  PACKAGE OPTION  TAPE AND REEL  Option 6  10.16 mm Option 7  Option 9							
AGENCY		V <sub>DRM</sub> 400		V <sub>DRM</sub> 600			
CERTIFIED/PACKAGE	TRIGGER CURRENT, I <sub>FT</sub> (mA)						
UL, cUL	1.6	2	3	1.6	2	3	
DIP-6	VO4154D	VO4154H	VO4154M	VO4156D	VO4156H	VO4156M	
DIP-6, 400 mil, option 6	VO4154D-X006	VO4154H-X006	VO4154M-X006	VO4156D-X006	VO4156H-X006	VO4156M-X006	
SMD-6, option 7	VO4154D-X007T	VO4154H-X007T	VO4154M-X007T	VO4156D-X007T	VO4156H-X007T (1)	VO4156M-X007T	
UL, cUL, VDE	1.6	2	3	1.6	2	3	
DIP-6, 400 mil, option 6	-	-	-	-	VO4156H-X016	- 1	
SMD-6, option 7	-	-	-	VO4156D-X017T	-	-	

#### Note

• Also available in tubes, do not put "T" to the end



<b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	PART	SYMBOL	VALUE	UNIT			
INPUT								
Reverse voltage			V <sub>R</sub>	6	V			
Forward current			I <sub>F</sub>	60	mA			
Surge current			I <sub>FSM</sub>	2.5	Α			
Power dissipation			P <sub>diss</sub>	100	mW			
Derate from 25 °C				1.33	mW/°C			
OUTPUT								
Peak off-state voltage		VO4154D/H/M	$V_{DRM}$	400	V			
		VO4156D/H/M	$V_{DRM}$	600	V			
RMS on-state current			I <sub>TM</sub>	300	mA			
Total power dissipation			P <sub>diss</sub>	500	mW			
Derate from 25 °C				6.6	mW/°C			
COUPLER								
Storage temperature range			T <sub>stg</sub>	-55 to +150	°C			
Ambient temperature range			T <sub>amb</sub>	-55 to +100	°C			
Soldering temperature	Max. ≤ 10 s dip soldering ≥ 0.5 mm from case bottom		T <sub>sld</sub>	260	°C			

#### Note

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
maximum ratings for extended periods of the time can adversely affect reliability

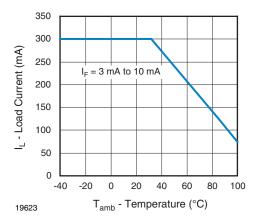


Fig. 1 - Recommended Operating Condition



THERMAL CHARACTERISTICS			
PARAMETER	SYMBOL	VALUE	UNIT
LED power dissipation	P <sub>diss</sub>	100	mW
Output power dissipation	P <sub>diss</sub>	500	mW
Maximum LED junction temperature	T <sub>jmax.</sub>	125	°C
Maximum output die junction temperature	T <sub>jmax.</sub>	125	°C
Thermal resistance, junction emitter to board	$\theta_{JEB}$	150	°C/W
Thermal resistance, junction emitter to case	$\theta_{JEC}$	139	°C/W
Thermal resistance, junction detector to board	$\theta_{JDB}$	78	°C/W
Thermal resistance, junction detector to case	$\theta_{JDC}$	103	°C/W
Thermal resistance, junction emitter to junction detector	$\theta_{JED}$	496	°C/W
Thermal resistance, case to ambient	$\theta_{CA}$	3563	°C/W

#### Note

The thermal characteristics table above were measured at 25 °C and the thermal model is represented in the thermal network below. Each
resistance value given in this model can be used to calculate the temperatures at each node for a given operating condition. The thermal
resistance from board to ambient will be dependent on the type of PCB, layout and thickness of copper traces. For a detailed explanation
of the thermal model, please reference Vishay's Thermal Characteristics of Optocouplers application note

<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT							
Forward voltage	I <sub>F</sub> = 10 mA		$V_{F}$	-	1.2	1.4	V
Reverse current	V <sub>R</sub> = 6 V		I <sub>R</sub>	-	0.1	10	μΑ
Input capacitance	V <sub>F</sub> = 0 V, f = 1 MHz		C <sub>I</sub>	-	25	-	pF
OUTPUT							
Repetitive peak off-state voltage	1004	VO4154D/H/M	$V_{DRM}$	400	-	-	V
nepetitive peak oil-state voltage	$I_{DRM} = 100 \mu A$	VO4156D/H/M	$V_{DRM}$	600	-	-	V
Off-state current	$V_D = V_{DRM}$ , $I_F = 0$ A		I <sub>DRM</sub>	-	-	100	μΑ
On-state voltage	$I_T = 300 \text{ mA}$		$V_{TM}$	-	-	3	V
On-state current	PF = 1, V <sub>T(RMS)</sub> = 1.7 V		I <sub>TM</sub>	-	-	300	mA
Off-state current in inhibit state	$I_F = 2 \text{ mA}, V_{DRM}$		I <sub>DINH</sub>	-	-	200	μΑ
Holding current			I <sub>H</sub>	-	-	500	μΑ
Zero cross inhibit voltage	I <sub>F</sub> = rated I <sub>FT</sub>		$V_{IH}$	-	-	20	V
Critical rate of rise of off-state voltage	V <sub>D</sub> = 0.67 V <sub>DRM</sub> , T <sub>J</sub> = 25 °C		dV/dt <sub>cr</sub>	5000	-	-	V/µs
Critical rate of rise of on-state			dV/dt <sub>cr</sub>	8	-	-	A/µs
COUPLER							
		VO4154D	I <sub>FT</sub>	-	-	1.6	mA
		VO4154H	I <sub>FT</sub>	-	-	2	mA
LED trigger current, current required to latch output	V <sub>D</sub> = 3 V	VO4154M	I <sub>FT</sub>	-	-	3	mA
	V <sub>D</sub> = 3 V	VO4156D	I <sub>FT</sub>	-	-	1.6	mA
		VO4156H	I <sub>FT</sub>	-	-	2	mA
		VO4156M	I <sub>FT</sub>	-	-	3	mA
Common mode coupling capacitance			ССМ	=	0.01	-	pF
Capacitance (input to output)	f = 1 MHz, V <sub>IO</sub> = 0 V		C <sub>IO</sub>	-	0.8	-	рF

### Note

Minimum and maximum values were tested requirements. Typical values are characteristics of the device and are the result of engineering
evaluations. Typical values are for information only and are not part of the testing requirements

SAFETY AND INSULATION RATINGS							
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT			
Climatic classification	According to IEC 68 part 1		55 / 100 / 21				
Comparative tracking index		CTI	175				
Maximum rated withstanding isolation voltage	t = 1 min	V <sub>ISO</sub>	4420	V <sub>RMS</sub>			
Maximum transient isolation voltage		V <sub>IOTM</sub>	8000	V <sub>peak</sub>			
Maximum repetitive peak isolation voltage		V <sub>IORM</sub>	890	V <sub>peak</sub>			
Isolation resistance	V <sub>IO</sub> = 500 V, T <sub>amb</sub> = 25 °C	R <sub>IO</sub>	≥ 10 <sup>12</sup>	Ω			
Isolation resistance	V <sub>IO</sub> = 500 V, T <sub>amb</sub> = 100 °C	R <sub>IO</sub>	≥ 10 <sup>11</sup>	Ω			
Output safety power		P <sub>SO</sub>	500	mW			
Input safety current		I <sub>SI</sub>	250	mA			
Safety temperature		T <sub>S</sub>	175	°C			
Creepage distance			≥ 7	mm			
Clearance distance			≥ 7	mm			
Insulation thickness		DTI	≥ 0.4	mm			
Pollution degree (DIN VDE 0109)			2				

#### Note

### TYPICAL CHARACTERISTICS (T<sub>amb</sub> = 25 °C, unless otherwise specified)

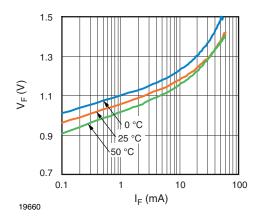


Fig. 2 - Diode Forward Voltage vs. Forward Current

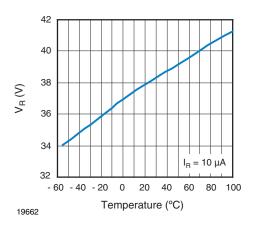


Fig. 3 - Diode Reverse Voltage vs. Temperature

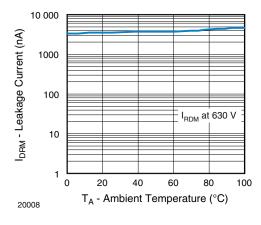


Fig. 4 - Leakage Current vs. Ambient Temperature

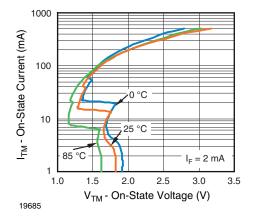


Fig. 5 - On-State Current vs. On-State Voltage

As per IEC 60747-5-5, § 7.4.3.8.2, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with
the safety ratings shall be ensured by means of protective circuits.

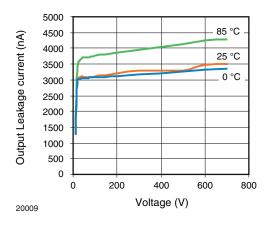


Fig. 6 - Output Off Current (Leakage) vs. Voltage

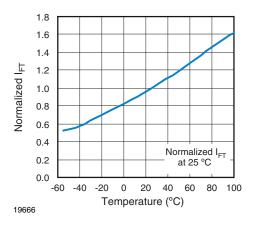


Fig. 7 - Normalized Trigger Input Current vs. Temperature

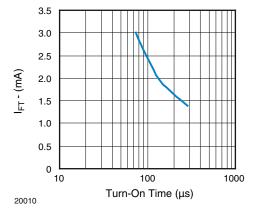


Fig. 8 -  $I_{FT}$  (mA) vs. Turn-On Time ( $\mu$ s)

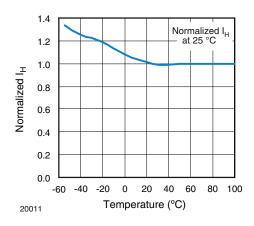


Fig. 9 - Normalized Holding Current vs. Temperature

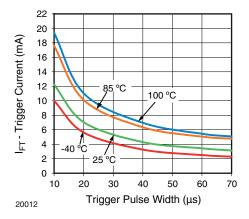
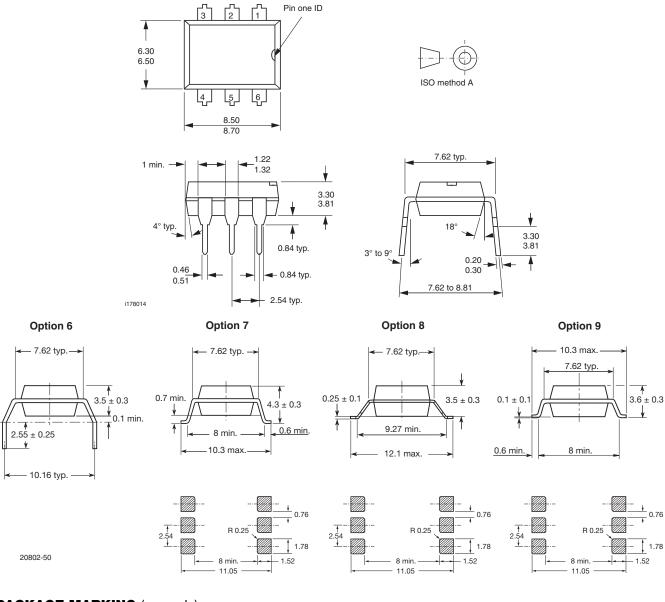


Fig. 10 - IFT vs. LED Pulse Width

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### **PACKAGE DIMENSIONS** in millimeters



### **PACKAGE MARKING** (example)



#### Notes

- Only options 1, 7, and 8 are reflected in the package marking
- The VDE Logo is only marked on option 1 parts
- Tape and reel suffix (T) is not part of the package marking



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